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Substitute for	Form 1449A/PTO			Complete if Known			
				Application Number	Unknown		
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STATEMENT BY APPLICANT				First Named Inventor	Wan-Thai, Hsu, et al.		
ļ				Group Art Unit	Unknown		
] ('use as many sheet	s as ne	ecessary)	Examiner Name	Unknown		
Sheet 1 of 2		Attorney Docket Number	UOM 0210 PUSP 1				

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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ² Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

Substitute for Form 1449B/PTO					Complete if Known					
11150	-	ATION	104		Application Number	Unknown				
	_			CLOSURE	Filing Date	Herewith				
SIA		IENI DI	AP	PLICANT	First Named Inventor	Wan-Thai Hsu, et al.				
					Group Art Unit	Unknown				
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